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# lodide/triiodide redox shuttle-based additives for high-performance perovskite solar cells by simultaneously passivating the cation and anion defects $\dagger$ 

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#### Abstract

Halide perovskite solar cells (PSCs) have received remarkably increasing interests due to their facile fabrication procedures, use of cost-effective raw materials, and high power conversion efficiencies (PCEs) during the past 10 years. Nevertheless, the state-of-the-art organic-inorganic PSCs suffer from high defect concentration and inferior humid/thermal stability, significantly restricting the widespread applications of PSCs. More specifically, point defects including metallic lead $\left(\mathrm{Pb}^{0}\right)$ and halide iodine $\left(1^{0}\right)$ are easily generated in $\mathrm{Pb} / \mathrm{l}$-based PSCs during fabrication processes and operational conditions due to the inferior interaction between the anions and cations in halide perovskites and promote detrimental carrier recombination and ion migration, leading to inferior PCEs and durability of the PSCs. Herein, to tackle the above-mentioned issues, iodide/triiodide $\left(I^{-} / I_{3}^{-}\right)$redox shuttles as a new additive were introduced to simultaneously passivate the cation and anion defects of methylammonium lead iodide ( $\mathrm{MAPb}_{3}$ )-based PSCs. In particular, $1^{-} / I_{3}^{-}$redox shuttles play a vital role in regenerating the cation ( $\mathrm{Pb}^{0}$ ) and anion ( $1^{\circ}$ ) defects through the redox cycles of $\mathrm{Pb}^{0} / \mathrm{Pb}^{2+}$ and $\mathrm{I}^{0} / I^{-}$. Consequently, the cell with an optimized amount of $\mathrm{I}^{-} / \mathrm{I}_{3}^{-}$additive generated a superior PCE of $20.4 \%$, which was $12 \%$ higher than the pristine device $(18.2 \%)$. Furthermore, the introduction of the $\mathrm{I}^{-} / \mathrm{I}_{3}^{-}$additive remarkably improved the humid and thermal stability of $\mathrm{MAPbl}_{3}$-based PSCs. This work manifests the importance of the design of redox shuttle-based additives to boost the efficiency and durability of organic-inorganic PSCs.


## 1. Introduction

Developing photovoltaic cells is regarded as one of the most effective approaches to conquer the challenges associated with global energy demands and environmental pollution by efficiently utilizing the abundant, renewable, and clean solar energy. ${ }^{1}$ Among various photovoltaic cells (solar cells), organic-inorganic halide perovskite solar cells (PSCs) have received significant attention because of the ultrafast boost in the power conversion efficiencies (PCEs) from $3.8 \%$ to $25.7 \%$ in the past 13 years. ${ }^{2,3}$ More specifically, the high PCEs of organic-inorganic PSCs mainly originate from the unique optical/electronic properties of $\mathrm{Pb} / \mathrm{I}$-based organic-inorganic

[^0]perovskites as light absorbers, such as their tunable band gaps, large light-absorption coefficient, long carrier-diffusion length, and excellent carrier mobility. ${ }^{4-8}$ In particular, $\mathrm{Pb} /$ I-based organic-inorganic perovskites with $\mathrm{CH}_{3} \mathrm{NH}_{3}{ }^{+}\left(\mathrm{MA}^{+}\right)$ cation, $\mathrm{CH}_{3}\left(\mathrm{NH}_{2}\right)_{2}{ }^{+}\left(\mathrm{FA}^{+}\right)$cation, and mixed cations at the A-site have recently exhibited high PCEs of $22-25 \% .{ }^{9}$ However, the estimated lifetime of encapsulated PSCs is far away from commercial silicon-based solar cells, which is mainly attributed to the weak interaction between cations and anions in halide perovskites, leading to inferior stability under various conditions, such as humidity, oxygen, ultraviolet (UV) light, and high temperatures. ${ }^{10-15}$

Several strategies such as encapsulation, adding a UV filter, and surface modification have been reported to alleviate the performance degradation of PSCs by temporarily excluding external environmental factors. ${ }^{16-21}$ However, some unavoidable factors such as light illumination, heat, and electric field under the operation conditions of PSCs are also critical elements in the degradation of $\mathrm{Pb} / \mathrm{I}$-based organic-inorganic perovskites induced by the breaking of the lattice bonding of $\mathrm{I}^{-}$and $\mathrm{Pb}^{2+}$ ions. ${ }^{22,23}$ It has been reported that $\mathrm{I}^{-}$and $\mathrm{Pb}^{2+}$ are
easily transformed to $\mathrm{I}^{0}$ and $\mathrm{Pb}^{0}$ (point defects) under hightemperature or illumination conditions, which not only act as carrier-recombination centers but can also accelerate the decomposition of $\mathrm{Pb} / \mathrm{I}$-based halide perovskites, leading to inferior PCEs and device lifetime. ${ }^{24,25}$ Point defects are considered as deep-level defects in PSCs and can capture and annihilate photoinduced electrons, leading to nonradiative carrier recombination, while most of the energy generated in the carrier annihilation is released into the halide perovskite lattice in the form of phonons. Such nonradiative carrier recombination will reduce the steady-state density, diffusion length, and lifetime of the photoexcited carriers, leading to serious performance degradation and the hysteresis of PSCs. ${ }^{26,27}$ To tackle the crucial issues of point defects in organic-inorganic $\mathrm{Pb} / \mathrm{I}$-based PSCs, tremendous attempts have been made recently such as additive engineering and surface passivation. ${ }^{28-40}$ Additives with functional groups such as $\mathrm{O}^{-}$, N -, or S-donors introduced into the perovskite precursor solution can coordinate with unpaired $\mathrm{Pb}^{2+}$ and stabilize Pb atoms in the perovskite lattice. ${ }^{41}$ In particular, metal/organic halide salt additives such as NaX, CsX, KX, RbX, MAX, and FAX (where $\mathrm{X}=\mathrm{F}, \mathrm{Cl}, \mathrm{Br}$ ) have been added in to the precursor solution and/or the lattice of halide perovskites, showing two main functions: (1) cations with a suitable radius can occupy the A-site to stabilize the perovskite structure and adjust its band gaps and photoelectric properties and (2) anions anchor $\mathrm{Pb}^{2+}$ through hydrogen bonds to inhibit the movement and immigration of $\mathrm{Pb}^{2+}$ cations. ${ }^{42}$ On the other hand, the surface modification of perovskite films aims to passivate grain boundaries and/or surface defects, forming a protective layer and constructing well-matched energy levels for PSCs. ${ }^{43,44}$ It should be noted that most of the used additives and surface modifiers are sacrificial agents nowadays, which are not able to continuously passivate the newly formed defects during the operation of PSCs. Thus, the continuous and efficient elimination of newly generated defects is highly crucial for extending the lifetime of PSCs.

Several sustainably utilized agents have attracted significant attention for removing the regenerated defects, which would be beneficial for promoting the lifetimes of PSCs. ${ }^{42,45,46}$ For instance, Shi et al. introduced spiropyran molecules as a capping layer on the perovskite film, which incessantly passivated the renewable Pb vacancies in $\mathrm{FAPbI}_{3}$-based PSCs, leading to much improved PCEs and long-term stability under sunlight illumination. ${ }^{42}$ In another work, Wang et al. reported that the $\mathrm{Eu}^{3+} / \mathrm{Eu}^{2+}$ redox pair could continuously oxidize $\mathrm{Pb}^{0}$ and reduce $I^{0}$ defects circularly in FAPbI $_{3}$-based PSCs to achieve enhanced PCEs and operational durability. ${ }^{41}$ Similarly, the introduction of tributyl phosphine (TBUP)/tributyl phosphine oxide (TBPO) redox couples could efficiently reduce the concentrations of $\mathrm{Pb}^{0}$ and $\mathrm{I}^{0}$ defects in the fabrication processes and the operational conditions of $\mathrm{FAPbI}_{3}$-based PSCs, significantly improving the thermal stability. ${ }^{46}$ In addition, triiodide $\left(\mathrm{I}_{3}{ }^{-}\right)$species have also been reported to decrease the iodide vacancies in $\mathrm{FAPbI}_{3}$-based PSCs to achieve a high PCE of $22.1 \% .{ }^{47}$ In this work, $\mathrm{I}^{-} / \mathrm{I}_{3}{ }^{-}$redox shuttles as a new additive
were introduced into a perovskite precursor solution of $\mathrm{MAPbI}_{3}$-based PSCs, simultaneously passivating the cation and anion defects by regenerating the $\mathrm{Pb}^{0}$ and $\mathrm{I}^{0}$ defects through the redox cycles of $\mathrm{Pb}^{0} / \mathrm{Pb}^{2+}$ and $\mathrm{I}^{0} / \mathrm{I}^{-}$. As a result, after optimizing the amount of $\mathrm{I}^{-} / \mathrm{I}_{3}{ }^{-}$additive, the $\mathrm{MAPbI}_{3}$-based cell generated a much better PCE of $20.4 \%$ than that of the pristine cell (18.2\%). Furthermore, the moisture and hightemperature stability of the $\mathrm{MAPbI}_{3}$-based PSCs were also significantly enhanced after introducing the $\mathrm{I}^{-} / \mathrm{I}_{3}{ }^{-}$redox couplebased additive. The current study can provide some valuable insights for the rational design of redox couple-based additives for achieving high-performance PSCs.

## 2. Experimental

### 2.1 Cell fabrication

The $\mathrm{F}^{-}$-doped $\mathrm{SnO}_{2}$ ( FTO ) glasses ( 2.2 mm -thick, $\sim 7 \Omega \mathrm{sq}^{-1}$ ) were sequentially cleaned by acetone, isopropanol, deionized water, and ethanol for half an hour, respectively, then dried by an inert gas and further treated in oxygen plasma for 5 min . A compact $\mathrm{TiO}_{2}\left(\mathrm{c}-\mathrm{TiO}_{2}\right)$ layer was fabricated on the cleaned FTO substrate by spin-coating the titanium diisopropoxide bis (acetylacetonate) $/ n$-butanol solution, which was further annealed at $500{ }^{\circ} \mathrm{C}$ for half an hour in air. A mesoporous $\mathrm{TiO}_{2}$ $\left(\mathrm{m}-\mathrm{TiO}_{2}\right)$ layer was subsequently fabricated on the $\mathrm{c}-\mathrm{TiO}_{2}$ layer by spin-coating the $\mathrm{TiO}_{2}$ paste (30NR-D) dispersed in ethanol, which was subsequently annealed at $500^{\circ} \mathrm{C}$ for half an hour in air. Next, $0.6 \mathrm{M} \mathrm{I}^{-} / \mathrm{I}_{3}{ }^{-}$solution was prepared by a mixed solid iodine ( $\mathrm{I}_{2}$ ) and 1-butyl-3-methylimidazolium iodide in mixed dimethyl sulfoxide (DMSO)/N,N-dimethylformamide (DMF) solution. The $\mathrm{MAPbI}_{3}$ precursor solution was prepared by mixing MAI and $\mathrm{PbI}_{2}$ in DMF/DMSO ( $7 / 3, \mathrm{v} / \mathrm{v}$ ) solution. Then, $\mathrm{I}^{-} / \mathrm{I}_{3}{ }^{-}$solutions at fixed volume ratios of $1 \%, 2 \%$, and $3 \%$ were added in to the perovskite solution, and the corresponding perovskite films and PSCs were denoted as $1 \%$-redox, $2 \%$ redox, and $3 \%$-redox, respectively. For the preparation of the hole-transporting layer (HTL), 2,2',7,7'-tetrakis( $N, N$-di- $p$-meth-oxyphenylamine)-9,9'-spirobifluorene (spiro-OMeTAD), FK209, 4-tert-butylpyridine, and Li-TFSI were dissolved in chlorobenzene at fixed proportions. ${ }^{29}$ The fabrications of the perovskite layer and HTL were sequentially conducted in the glove box. ${ }^{29}$ Last, the Ag electrode with a thickness of 100 nm and an active area of $0.0625 \mathrm{~cm}^{2}$ was thermally evaporated on the HTL surface. Carbon-based HTL-free devices were fabricated by doctor blading under ambient conditions for the thermal stability test.

### 2.2 Characterizations

A source meter (Keithley 2400) combined with a solar simulator (Zolix, SS150A) was used to obtain the photocurrent density-voltage ( $J-V$ ) curves under the condition of AM 1.5 G irradiation ( $100 \mathrm{~mW} \mathrm{~cm}{ }^{-2}$ ). X-ray diffraction (XRD) patterns of the various films were tested by X-ray diffractometry ( $\mathrm{Cu} \mathrm{K} \alpha$ radiation, Rigaku Co., Ltd). The surface and cross-sectional microstructures (morphology and roughness) of various films
were tested by scanning electron microscopy (SEM, Hitachi S-4800) and atomic force microscopy (AFM, SmartSPM, Horiba), respectively. The surface elemental states of various perovskite films were studied by X-ray photoelectron spectroscopy (XPS, Al K $\alpha$ X-ray source, PHI5000 Versa Probe). The time-resolved photoluminescence (TRPL) and photoluminescence (PL) spectra were measured by fluorescence spectrophotometry (Edinburgh Instruments, FLS980, and PerkinElmer, FL6500, respectively). UV-Vis-NIR spectrophotometry (PerkinElmer, Lambda 750S) was used to obtain the UV-vis spectra of various films and cells. The external quantum efficiency (EQE) profiles were tested using a Solar Cell Scan 100 instrument (Zolix). The electrochemical impedance spectroscopy (EIS) profiles were measured on an electrochemical station (CHI760) under dark conditions with a frequency range of $10^{6}-0.1 \mathrm{~Hz}$.

## 3. Results and discussion

A traditional $\mathrm{I}^{-} / \mathrm{I}_{3}{ }^{-}$redox shuttle has been extensively utilized in dye-sensitized solar cells to efficiently regenerate the dye. ${ }^{48,49}$ It has been reported that $\mathrm{I}^{-}$anion-based additives, such as CsI, KI, and $\mathrm{PbI}_{2}$, can reduce the amounts of $\mathrm{Pb}^{0}$ and $\mathrm{I}^{0}$ defects. ${ }^{50-52}$ However, these sacrificial additives are not able to eliminate renewable (newly formed) point defects of PSCs under operational conditions. On this basis, $\mathrm{I}^{-} / \mathrm{I}_{3}{ }^{-}$-based redox shuttles were introduced here as additives in perovskite films to continuously passivate the $\mathrm{Pb}^{0}$ and $\mathrm{I}^{0}$ defects. To prepare the $\mathrm{I}^{-} / \mathrm{I}_{3}{ }^{-}$-based solution, $\mathrm{I}_{2}$ and 1-butyl-3-methylimidazolium iodide were dissolved in DMF/DMSO solution with the formation of $\mathrm{I}_{3}{ }^{-}$based on the equation: $\mathrm{I}_{2}+\mathrm{I}^{-} \rightleftharpoons \mathrm{I}_{3}{ }^{-}$. Different
volume ratios of $\mathrm{I}^{-} / \mathrm{I}_{3}{ }^{-}$redox shuttles ( $1 \%, 2 \%$, and $3 \%$ ) were added into perovskite precursor solution, with the typical digital photographs shown in Fig. S1. $\dagger$ Compared with the perovskite solution without adding the redox additive, the color of the precursor solution became deeper yellow after the addition of $\mathrm{I}^{-} / \mathrm{I}_{3}{ }^{-}$additives. A typical cross-sectional SEM image of the fabricated PSCs in this study with the configuration of $\mathrm{FTO} / \mathrm{c}-\mathrm{TiO}_{2} / \mathrm{m}^{-\mathrm{TiO}_{2}} /$ perovskite/spiro-OMeTAD/ Ag is shown in Fig. $\mathrm{S} 2 \dagger$ and the thickness of the perovskite layer was around 400 nm . The photocurrent-voltage $(J-V)$ curves of the bestefficiency devices fabricated without and with the redox additives are shown in Fig. 1a and the corresponding photovoltaic parameters are displayed in Table S1 and Fig. S3. $\dagger$ It was found that the PCEs of the $\mathrm{MAPbI}_{3}$-based cells first increased then decreased with the increasing amount of redox additives (Fig. 1b and c). The best-performing 2\%-redox cell produced a superior PCE of $20.4 \%$ with an open-circuit voltage ( $V_{\text {oc }}$ ) of 1.11 V , a short-circuit current $\left(J_{\mathrm{sc}}\right)$ of $23.8 \mathrm{~mA} \mathrm{~cm}{ }^{-2}$, and a fill factor ( FF ) of 0.770 , while the pristine device generated a PCE of $18.2 \%$ with a $V_{\text {oc }}$ of 1.08 V , a $J_{\mathrm{sc}}$ of $22.8 \mathrm{~mA} \mathrm{~cm}{ }^{-2}$, and an FF of 0.744 . It should be noted that a slight decrease in the cell performance was observed in the $3 \%$-redox cell, which may be attributed to the reaction between the excessive redox additives and mobile ions in perovskite films with the regeneration of $\mathrm{I}_{2}{ }^{24}$ Fig. 1d displays the EQE curves of the pristine and $2 \%{ }^{-}$ redox cells, whereby the $2 \%$-redox device exhibited higher EQE values than those of the pristine cell over the whole visible light range ( $380-780 \mathrm{~nm}$ ), indicating the improved lightabsorption capability of the $2 \%$-redox cell. ${ }^{53}$ In addition, the $2 \%$-redox cell displayed a superior integrated $J_{\text {sc }}$ value of $23.4 \mathrm{~mA} \mathrm{~cm}^{-2}$ compared to that of the pristine cell $(21.8 \mathrm{~mA}$ $\mathrm{cm}^{-2}$ ), agreeing well with the $J-V$ results.


Fig. 1 (a) J-V curves of the cells without and with redox additives at different volume ratios. PCE distributions of 20 devices without and with redox additives at different volume ratios: (b) histogram and (c) box chart. (d) EQE spectra and integrated current densities of the pristine and $2 \%-$ redox cells.

The influence of the redox additives on the crystal structure and crystallinity of the perovskite films was investigated by XRD. As depicted in Fig. 2a, the major characteristic peaks of $\mathrm{MAPbI}_{3}$ perovskites at $14.29^{\circ}$ and $28.38^{\circ}$ were assigned to the (110) and (220) planes and exhibited no obvious shifts, indicating the introduction of redox additives showed no obvious influence on the crystal structure of the $\mathrm{MAPbI}_{3}$ perovskites. ${ }^{54,55}$ Furthermore, the redox additive-modified perovskite films displayed much higher intensities for the (110) and (220) peaks in the XRD patterns, suggesting that the redox additive enhanced the crystallinity of the perovskite film. We further compared the full width at half maximum (FWHM) values of the (110) diffraction peak of the pristine and various redox additive-modified perovskite films, and the results are shown in Fig. 2b. It was found that the introduction of redox additives effectively reduced the FWHM value of the (110) peak, suggesting the much improved crystallinity of the perovskite film induced by the redox additive. In addition, based on the calculated crystallite sizes of various perovskite films by Scherrer's equation in Fig. 2b, ${ }^{56,57}$ the crystallite sizes of the perovskite films first increased and then decreased with the increasing amount of redox additive. In particular, the $2 \%$ redox film exhibited the smallest FWHM and largest crystallite sizes, demonstrating a much improved perovskite film quality induced by the proper concentration of redox additive. SEM
and AFM were employed to investigate the impacts of the redox additives on the morphology and surface roughness of the perovskite films. As displayed in Fig. 2c-f, the top-view SEM images revealed that the redox additive with a proper concentration effectively increased the grain sizes, and reduced the amounts of pinholes, cracks, and grain boundaries of the pristine $\mathrm{MAPbI}_{3}$ film. As displayed in Fig. $2 \mathrm{~g}-\mathrm{j}$ and $\mathrm{S} 4 \mathrm{a}-\mathrm{d}, \dagger$ the pristine, $1 \%$-redox, $2 \%$-redox, and $3 \%$-redox perovskite films exhibited root-mean-square (RMS) roughness values of 51.5 , $42.5,36.7$, and 52.6 nm , respectively. The remarkably reduced RMS value of the $2 \%$-redox film indicated a compact film surface with less traps and pinholes, providing better contact between the perovskite film and HTL to promote the interfacial carrier transport. ${ }^{28,30}$

XPS was used to explore the influences of the $\mathrm{I}^{-} / \mathrm{I}_{3}{ }^{-}$-based redox additives on the surface elemental states of various ions of perovskite films (Fig. $\mathrm{S} 5 \dagger$ ). As depicted in Fig. 3a, $\mathrm{Pb}^{2+} 4 \mathrm{f}_{5 / 2}$ and $\mathrm{Pb}^{2+} 4 \mathrm{f}_{7 / 2}$ were located at binding energies (BEs) of 142.8 and 137.9 eV , respectively, while the peaks at BEs of 141.1 and 136.2 eV were assigned to $\mathrm{Pb}^{0}$ species. ${ }^{58,59}$ It was obvious that a considerable amount of $\mathrm{Pb}^{0}$ defects was distributed on the surface of pristine perovskite film, while the $\mathrm{Pb}^{0}$ content of the $2 \%$-redox film was significantly reduced. The intensity ratio of $\mathrm{Pb}^{0} /\left(\mathrm{Pb}^{0}+\mathrm{Pb}^{2+}\right)$ was further calculated to investigate the $\mathrm{Pb}^{0}$ content in the pristine and $2 \%$-redox films. As shown in


Fig. 2 (a) XRD patterns of perovskite films without and with redox additives. (b) FWHM values of the (110) diffraction peaks and crystalline sizes of perovskite films without and with redox additives. Top-view SEM and AFM images of (c and g) pristine, (d and h) 1\%-redox, (e and i) 2\%-redox, and (f and j) 3\%-redox films.


Fig. 3 (a) $\mathrm{Pb} 4 f$ XPS spectra, (b) $\mathrm{Pb}^{0} /\left(\mathrm{Pb}^{0}+\mathrm{Pb}^{2+}\right)$ and $\mathrm{I} / \mathrm{Pb}$ ratios, (c) I 3d XPS spectra of the pristine and $2 \%$-redox films. (d) Proposed mechanism of the $\mathrm{I}^{-} / I_{3}^{-}$-based redox additive on passivating the $\mathrm{Pb}^{0}$ and $\mathrm{I}^{\circ}$ defects via continuous regeneration and redox reactions.

Fig. 3b, the 2\%-redox film exhibited a much decreased $\mathrm{Pb}^{0} /$ $\left(\mathrm{Pb}^{0}+\mathrm{Pb}^{2+}\right)$ ratio of $3.28 \%$ compared with the pristine perovskite film $(8.00 \%)$ due to the effective oxidation of $\mathrm{Pb}^{0}$ defects by $I_{3}{ }^{-}$. As for the $I^{0}$ species, the exact $I^{0} /\left(I^{0}+I^{-}\right)$ratio was very difficult to obtain via peak fitting due to the volatility of $\mathrm{I}^{0}$ species during the annealing process. Thus, we adopted the I/ Pb ratios and BE shifts of $\mathrm{I} 3 \mathrm{~d}_{5 / 2}$ to reflect the concentration evolution of $I^{0}$ species in the pristine and $2 \%$-redox films. As depicted in Fig. 3c, the intensity ratios of I/Pb were 2.77 and 2.90 for the pristine and $2 \%$-redox films, respectively, indicating the smaller amount of $I^{0}$ species in the $2 \%$-redox film. ${ }^{44,45}$ Moreover, the shifts of the I $3 \mathrm{~d}_{5 / 2}$ XPS peaks to lower BEs in the $2 \%$-redox film also suggested the reduced amount of $I^{0}$ species. ${ }^{44}$ Accordingly, we proposed the oxidation-reduction mechanism of the $\mathrm{I}^{-} / \mathrm{I}_{3}{ }^{-}$redox shuttle in the $\mathrm{MAPbI}_{3}$ film based on the equations: $\mathrm{Pb}^{0}+\mathrm{I}_{3}{ }^{-} \rightarrow \mathrm{PbI}_{2}+\mathrm{I}^{-}$and $2 \mathrm{I}^{0}+\mathrm{I}^{-} \rightarrow$ $\mathrm{I}_{3}{ }^{-}$, as depicted in Fig. 3d. It could be concluded that the introduction of redox additives effectively reduced the amounts of $\mathrm{Pb}^{0}$ and $\mathrm{I}^{0}$ defects through continuous regeneration and redox reactions.

To examine the impacts of the $\mathrm{I}^{-} / \mathrm{I}_{3}{ }^{-}$redox shuttle-based additives on the light-absorption capacity and band gaps of $\mathrm{MAPbI}_{3}$ films, the UV-vis spectra of various $\mathrm{MAPbI}_{3}$ films were tested. As depicted in Fig. 4a, the addition of redox additives enhanced the light-absorption capacity of the perovskite films, while the optimized $2 \%$-redox film exhibited the highest lightabsorption intensity without obviously changing the band gap values ( 1.583 and 1.577 eV for the pristine and $2 \%$-redox films, as shown in Fig. $\mathrm{S} 6 \dagger$ ), which was attributed to the much enhanced quality and morphology of the $2 \%$-redox film, as evidenced by the SEM results. Based on the steady-state PL spectra of various $\mathrm{MAPbI}_{3}$ films deposited on an insulating substrate in Fig. 4b, compared with the PL spectra of the pris-
tine $\mathrm{MAPbI}_{3}$ film, the $1 \%$-redox film showed a blue-shift in the PL peak, while the $2 \%$-redox film exhibited a red-shift in the PL peak, which may have contributed to the increased $J_{\text {sc }}$ value of the corresponding $2 \%$-redox device. ${ }^{60,61}$ The higher PL peak intensity of the $2 \%$-redox film indicated that the introduction of redox additives effectively suppressed the amount of nonradiative recombination centers and slightly extended the light-absorption range of the perovskite films, which would be beneficial for the performance enhancement of the corresponding PSCs. ${ }^{62}$ In addition, the TRPL technique was conducted to investigate the carrier-transport capability of the perovskite films after introducing the redox additive. As shown in Fig. 4c, the average carrier lifetime values $(\tau)$ of the pristine and $2 \%$-redox films obtained from biexponential decay fitting (Table S $2 \dagger$ ) were 49.0 and 68.0 ns , respectively. ${ }^{63}$ This indicated that the redox additive remarkably inhibited the nonradiative carrier recombination by eliminating the deep-level defects, such as $\mathrm{Pb}^{0}$ and $\mathrm{I}^{0}$ species, which also contributed to the higher $V_{\text {oc }}$ value of the $2 \%$-redox cell. ${ }^{64,65}$ In order to explore the interfacial charge-transfer dynamics, EIS was conducted at 0.9 V under dark conditions. As depicted in Fig. 4d, the fitted Nyquist plots displayed a low-frequency arc, which was inversely proportional to the interfacial carrier-recombination degree. ${ }^{66}$ As could be seen, the $2 \%$-redox cell displayed a higher recombination resistance ( $R_{\text {rec }}$ ) value of $7776 \Omega$ than those of the pristine (2031 $\Omega$ ), $1 \%$-redox (3694 $\Omega$ ), and $3 \%-$ redox (6704 $\Omega$ ) cells, suggesting that the interfacial carrierrecombination process was remarkably inhibited by introducing a proper amount of the redox additive, which was beneficial for the photovoltaic performance.

The hole-defect densities $\left(N_{\mathrm{d}}\right)$ of the pristine and various redox additive-modified films were calculated by using the space-charge-limited current mode in hole-only PSCs with a


Fig. 4 (a) UV-vis absorption spectra of various perovskite films with and without redox additives. (b) PL and (c) TRPL spectra of different perovskite films with and without redox additives deposited on non-conductive substrates. (d) EIS spectra of devices with and without redox additives at 0.9 V in the dark. (e) Dark J-V curves of the hole-only devices with and without redox additives. (f) Dark J-V curves of the pristine and redox additivemodified cells.
configuration of FTO/PEDOT:PSS/perovskite/spiro-OMeTAD/Ag under dark conditions. The $N_{\mathrm{d}}$ values could be obtained from the equation: $N_{\mathrm{d}}=\frac{2 \varepsilon_{0} \varepsilon_{V_{\mathrm{TFL}}}}{e L^{2}}$, where $\varepsilon_{0}$ and $\varepsilon$ are the vacuum dielectric constant and relative permittivity, $V_{\text {TFL }}$ is the trapfilled limit voltage, $e$ is the elementary charge of electron, and $L$ is the thickness of the perovskite film $(\sim 400 \mathrm{~nm}) .{ }^{67}$

As depicted from Fig. 4e, the $V_{\text {TFL }}$ values of the pristine, $1 \%$-redox, $2 \%$-redox, and $3 \%$-redox cells were $0.50,0.38,0.20$, and 0.33 V , corresponding to $N_{\mathrm{d}}$ values of $6.36,4.84,2.54$, and $4.20 \times 10^{15} \mathrm{~cm}^{-3}$, respectively, further verifying the vital role of the redox additives on reducing the defects of the perovskite
film. Based on the dark $J-V$ curves of various PSCs in Fig. 4 f , the $2 \%$-redox cell exhibited the lowest dark current among the four cells, indicating a much reduced current loss due to the improved interfacial charge transfer induced by the suppressed defect concentration. ${ }^{30}$

As mentioned above, the $\mathrm{Pb}^{0}$ and $\mathrm{I}^{0}$ defects derived from the perovskite structure acted as nonradiative recombination centers to promote the detrimental ion migration, leading to severe performance degradation under humid and high-temperature conditions. ${ }^{24}$ The moisture and thermal stability of the pristine and $2 \%$-redox cells are displayed in Fig. 5a and b, respectively. As can be seen in Fig. 5a, the 2\%-redox cell exhibi-


Fig. 5 Normalized photovoltaic parameters of the pristine and $2 \%$-redox cells stored in humid air at (a) $25-30^{\circ} \mathrm{C}$ (with spiro-OMeTAD HTL) and (b) $85^{\circ} \mathrm{C}$ (HTL-free).
ted a superior PCE retention ratio of $\sim 78 \%$ after 864 h storage in ambient conditions at $25-30{ }^{\circ} \mathrm{C}$ and a relative humidity (RH) of $\sim 25 \%$, which was much better than that of the pristine cell (PCE retention ratio of $\sim 25 \%$ ) under the same conditions. HTL-free carbon-based PSCs were utilized to study the impacts of the redox additive on the thermal stability due to the unstable organic HTL. The thermal stability of the HTL-free carbon-based devices is depicted in Fig. 5b, where it can be seen that the $2 \%$-redox cell retained $46 \%$ of the primary PCE after aging at $85{ }^{\circ} \mathrm{C}$ in humid air (RH: 20\%) for 720 h , while the PCE of the pristine cell declined to $24 \%$ under the same conditions, which was mainly attributed to the rapidly degraded FF. As shown in Fig. S7 and Table S3, $\dagger$ the HTL-free $2 \%$-redox cell delivered a higher PCE of $10.3 \%$ than that of the unmodified cell ( $9.6 \%$ ), further indicating the superiority of the redox additive in boosting the cell performance. The above results suggested that the redox additives played a crucial role in improving the moisture and high-temperature durability of MAPbI ${ }_{3}$-based PSCs.

## 4. Conclusions

In summary, iodide/triiodide redox shuttles were employed as effective additives to simultaneously passivate the deep-level cation and anion defects (e.g., $\mathrm{Pb}^{0}$ and $\mathrm{I}^{0}$ ) by constructing redox cycles of $\mathrm{Pb}^{0} / \mathrm{Pb}^{2+}$ and $\mathrm{I}^{0} / \mathrm{I}^{-}$for the continuous regeneration of $\mathrm{Pb}^{0}$ and $\mathrm{I}^{0}$ defects, which effectively reduced the nonradiative carrier recombination and facilitated the interfacial carrier transport. In addition, the introduction of redox additives also enhanced the perovskite film quality by enlarging the grain sizes, increasing the crystallinity, reducing the amount of pinholes, and improving the light-absorption capability. As a result, the device with the optimized amount of redox additive generated a higher PCE of $20.4 \%$ than that of the pristine cell ( $18.2 \%$ ) due to the remarkable enhancement in $V_{\text {oc }}$ and FF values induced by the effective passivation of the deep-level $\mathrm{Pb}^{0}$ and $\mathrm{I}^{0}$ defects. Moreover, the redox additivemodified cell also showed much superior moisture/thermal durability to that of the unmodified cell and stability due to the improved perovskite film quality and suppressed defect concentration. This study provides a new and effective redox shuttle-based additive to eliminate the deep-level defects in perovskite films, simultaneously improving the PCEs and durability of $\mathrm{MAPbI}_{3}$-based PSCs, which can promote the widespread application of perovskite photovoltaics.

## Author contributions

Huimin Xiang: investigation, formal analysis, visualization, writing - original draft, data curation; Jingsheng He: formal analysis; Ran Ran: writing - review \& editing; Wei Zhou: funding acquisition, writing - review \& editing; Wei Wang: supervision, conceptualization, writing - review \& editing, funding acquisition, validation; Zongping Shao: supervision,
conceptualization, writing - review \& editing, funding acquisition.

## Conflicts of interest

The authors declare no conflict of interest.

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